## **PROGRAMME**

## October, 2

9.30 Registration

## 10.15 Paolo Cappelletti Award

10.30 **David Refaldi** (Politecnico di Milano) Exploring 3D NAND Flash memory operation in the cryogenic regime

11.15 **Rino Micheloni** (Avaneidi Spa, Italy) - **Cristian Zambelli** (University of Ferrara) Linking 3D NAND Flash with Solid State Drives reliability: a holistic device-to-system approach

12.00 Yiyi Wang (NVIDIA, Los Altos, California)

Beyond Traditional Simulation: A GPU-Powered and Al-Driven Framework for Memory Device Modeling

12.45 Lunch

14.00 Alessandro Grossi (Infineon, Padova)

RRAM for automotive applications: reliability challenges and outlook

14.45 **Sergiu Clima** (IMEC, Belgium)

Understand Atomic Mechanisms and Predict Superior OTS Materials for Selector-Only-Memory with First-Principles Simulations

15.30 Valeria Bragaglia (IBM, Zurich)

A Novel ReRAM for Analog Training/Inference Accelerator and BEOL Non-Volatile Memories

16.15 Coffee break

## October, 3

9.15 Thomas Boesch (STMicroelectronics)

eNVM vs SRAM In-Memory-Computing for embedded neural network processing

10.00 Alessandro Calderoni (Micron Technology)

Past, Present, and Future of DRAM Technology: Challenges, Innovations and Emerging Technologies

10.45 Coffee break

11.15 Asif Khan (Georgia Tech., Atlanta)

Pushing the limits of NAND scaling with Ferroelectrics

12.00 Pouya Esmaili Dokht (BSC, Barcelona)

MESS benchmark

12.45 Lunch

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